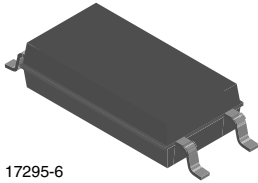
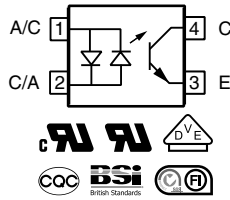


# Optocoupler, Phototransistor Output, AC Input, Low Input Current, 4 Pin LSOP, Long Creepage Mini-Flat Package



17295-6


**FEATURES**

- Low profile package
- High collector emitter voltage,  $V_{CEO} = 80\text{ V}$
- Isolation test voltage,  $5000\text{ V}_{RMS}$
- Low coupling capacitance
- High common mode transient immunity
- Material categorization:  
For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**DESCRIPTION**

The VOL628A has two GaAs infrared emitting diodes, which are optically coupled to a silicon planar phototransistor detector, and are incorporated in a 4 pin LSOP wide body package.

It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

The coupling device is designed for signal transmission between two electrically separated circuits.

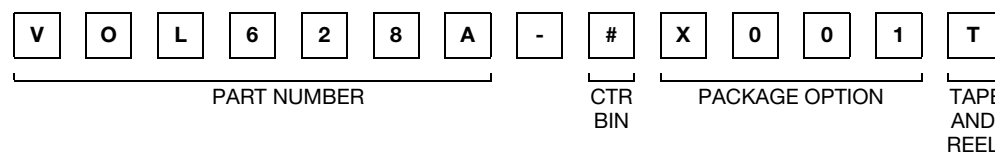
**APPLICATIONS**

- Telecom
- Industrial controls
- Battery powered equipment
- Office machines
- Programmable controllers

**AGENCY APPROVALS**

(All parts are certified under base model VOL628A)

- UL1577, file no. E76222
- cUL CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI: EN 60065:2002, EN 60950-1:2006
- FIMKO EN60950-1
- CQC: GB8898-2011, GB4943.1-2011

**ORDERING INFORMATION**


AGENCY CERTIFIED/PACKAGE	CTR (%)			
	1 mA			
<b>UL, cUL, BSI, FIMKO, CQC</b>	<b>50 to 600</b>	<b>40 to 80</b>	<b>63 to 125</b>	<b>100 to 200</b>
4 pin LSOP, mini-flat, long creepage	VOL628AT	VOL628A-1T	VOL628A-2T	VOL628A-3T
<b>UL, cUL, BSI, FIMKO, CQC, VDE (option 1)</b>	<b>50 to 600</b>	<b>40 to 80</b>	<b>63 to 125</b>	<b>100 to 200</b>
4 pin LSOP, mini-flat, long creepage	VOL628A-X001T	VOL628A-1X001T	VOL628A-2X001T	VOL628A-3X001T

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		$V_R$	6	V
Power dissipation		$P_{diss}$	100	mW
Forward current		$I_F$	$\pm 60$	mA
Junction temperature		$T_j$	125	$^{\circ}\text{C}$
<b>OUTPUT</b>				
Collector emitter voltage		$V_{CEO}$	80	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector current		$I_C$	50	mA
	$t_p/T = 0.5, t_p < 10\text{ ms}$	$I_C$	100	mA
Power dissipation		$P_{diss}$	150	mW
Junction temperature		$T_j$	125	$^{\circ}\text{C}$
<b>COUPLER</b>				
Isolation test voltage between emitter and detector	$t = 1\text{ min}$	$V_{ISO}$	5000	$V_{RMS}$
Total power dissipation		$P_{tot}$	250	mW
Storage temperature range		$T_{stg}$	- 55 to + 125	$^{\circ}\text{C}$
Ambient temperature range		$T_{amb}$	- 55 to + 110	$^{\circ}\text{C}$
Soldering temperature <sup>(1)</sup>	$\leq 10\text{ s}$	$T_{sld}$	260	$^{\circ}\text{C}$

**Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- <sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices.

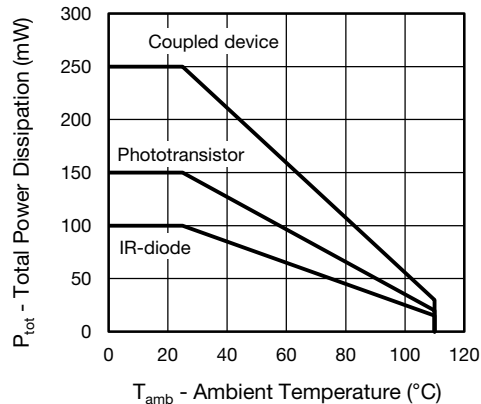


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>							
Forward voltage	$I_F = \pm 5\text{ mA}$		$V_F$		1.16	1.5	V
Reverse current	$V_R = 6\text{ V}$		$I_R$			100	$\mu\text{A}$
Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$		$C_O$		45		pF
<b>OUTPUT</b>							
Collector emitter leakage current	$V_{CE} = 10\text{ V}, I_F = 0\text{ A}$		$I_{CEO}$		10	200	nA
Collector emitter capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$		$C_{CE}$		7		pF
<b>COUPLER</b>							
Collector emitter saturation voltage	$I_C = 0.2\text{ mA}, I_F = \pm 1\text{ mA}$	VOL628A	$V_{CEsat}$		0.25	0.4	V
	$I_C = 0.2\text{ mA}, I_F = \pm 1\text{ mA}$	VOL628A-1T	$V_{CEsat}$		0.25	0.4	V
	$I_C = 0.32\text{ mA}, I_F = \pm 1\text{ mA}$	VOL628A-2T	$V_{CEsat}$		0.25	0.4	V
	$I_C = 0.5\text{ mA}, I_F = \pm 1\text{ mA}$	VOL628A-3T	$V_{CEsat}$		0.25	0.4	V
Coupling capacitance	$f = 1\text{ MHz}$		$C_C$		0.25		pF

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

**CURRENT TRANSFER RATIO** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$I_F = \pm 1\text{ mA}$ , $V_{CE} = 5\text{ V}$	VOL628A	CTR	50		600	%
		VOL628A-1	CTR	40		80	%
		VOL628A-2	CTR	63		125	%
		VOL628A-3	CTR	100		200	%

**SWITCHING CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn on time	$V_{CC} = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$	$t_{on}$		6		$\mu\text{s}$
Rise time	$V_{CC} = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$	$t_r$		3.5		$\mu\text{s}$
Turn off time	$V_{CC} = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$	$t_{off}$		5.5		$\mu\text{s}$
Fall time	$V_{CC} = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\text{ }\Omega$	$t_f$		5		$\mu\text{s}$

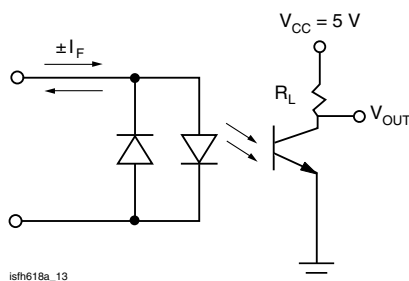


Fig. 2 - Test Circuit

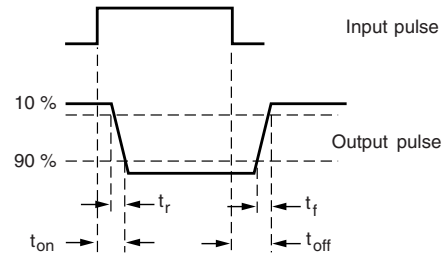


Fig. 3 - Test Circuit and Waveforms

**SAFETY AND INSULATION RATED PARAMETERS**

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, $t_{test} = 1\text{ s}$	$V_{pd}$	2			$\text{kV}_{peak}$
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60\text{ s}$ , $t_{test} = 10\text{ s}$ , (see figure 4)	$V_{IOTM}$			8	$\text{kV}_{peak}$
		$V_{pd}$	1.68			$\text{kV}_{peak}$
Insulation voltage		$V_{IORM}$			1050	$V_{peak}$
Insulation resistance	$V_{IO} = 500\text{ V}$ , $T_{amb} = 25\text{ }^{\circ}\text{C}$	$R_{IO}$	$10^{12}$			$\Omega$
	$V_{IO} = 500\text{ V}$ , $T_{amb} = 100\text{ }^{\circ}\text{C}$	$R_{IO}$	$10^{11}$			$\Omega$
	$V_{IO} = 500\text{ V}$ , $T_{amb} = 150\text{ }^{\circ}\text{C}$ (construction test only)	$R_{IO}$	$10^9$			$\Omega$
Safety rating - maximum input current		$I_{si}$			130	mA
Safety rating - maximum power dissipation		$P_{SO}$			265	mW
Safety rating - maximum ambient temperature		$T_{si}$			150	$^{\circ}\text{C}$
Clearance distance			8			mm
Creepage distance			8			mm
Insulation distance (internal)			0.4			mm

**Note**

- According to DIN EN 60747-5-5 (VDE 0884), § 7.4.3.8.2, (see figure 4). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

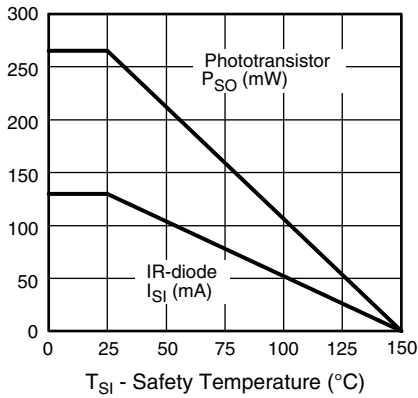


Fig. 4 - Derating Diagram

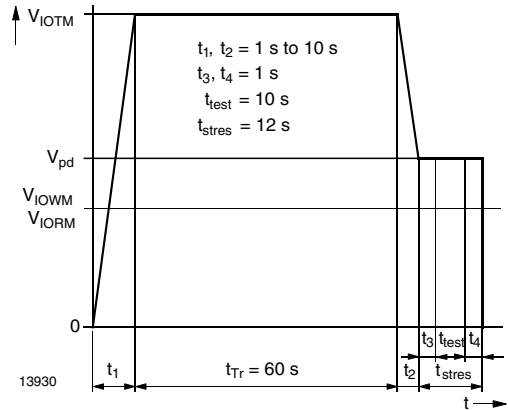


Fig. 5 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-5

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

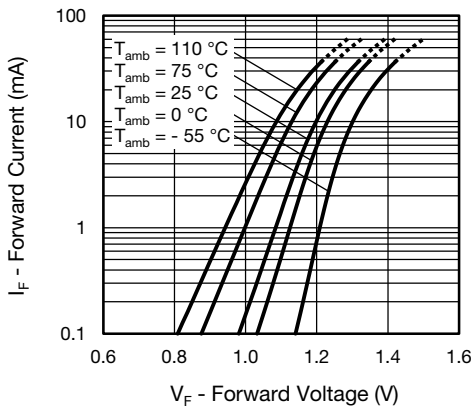


Fig. 6 - Forward Voltage vs. Forward Current

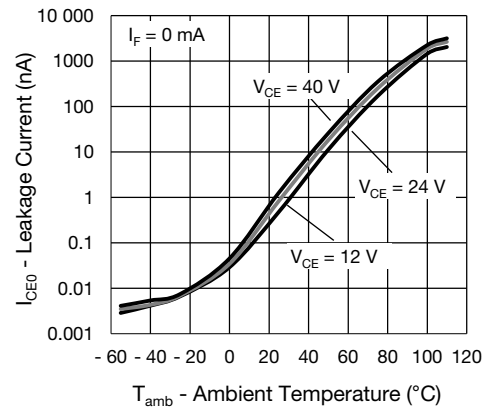


Fig. 8 - Collector Emitter Current vs. Ambient Temperature

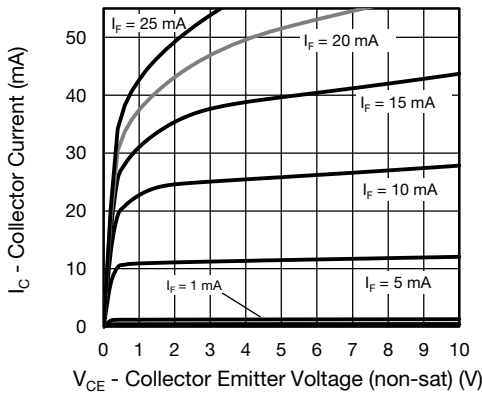


Fig. 7 - Collector Current vs. Collector Emitter Voltage (non-saturated)

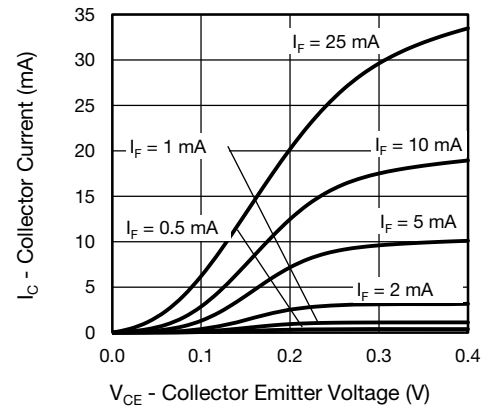


Fig. 9 - Collector Current vs. Collector Emitter Voltage (saturated)

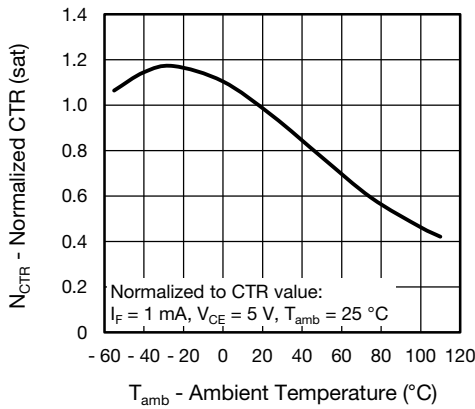


Fig. 10 - Normalized Current Transfer Ratio vs. Ambient Temperature (saturated)

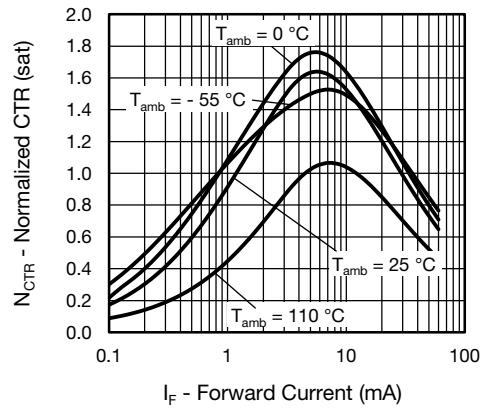


Fig. 13 - Current Transfer Ratio vs. Forward Current (non-saturated) Normalized to 1 mA at 25 °C

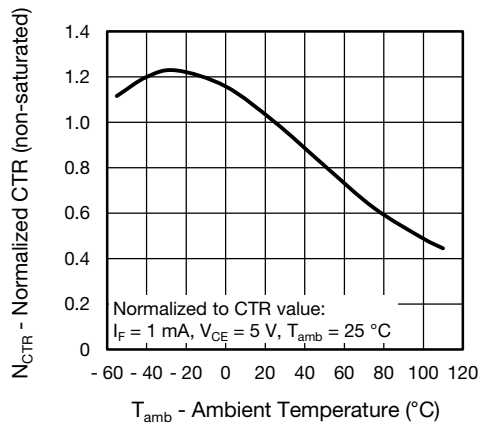


Fig. 11 - Normalized Current Transfer Ratio vs. Ambient Temperature (non-saturated)

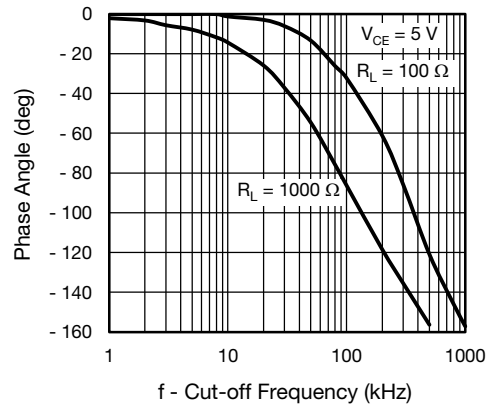


Fig. 14 -  $f_{CTR}$  vs. Phase Angle

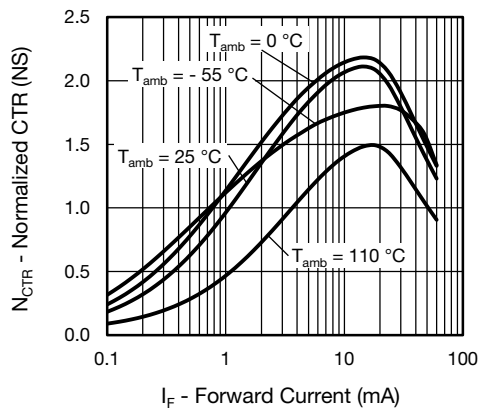


Fig. 12 - Current Transfer Ratio vs. Forward Current (saturated) Normalized to 1 mA at 25 °C

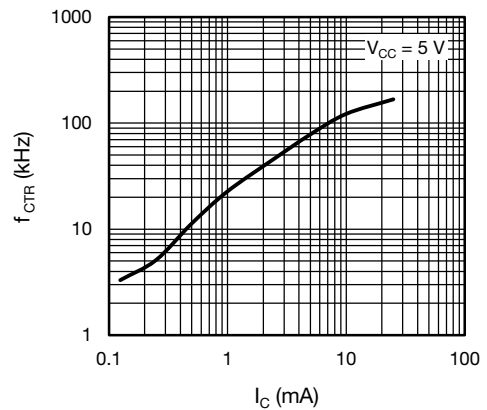


Fig. 15 - Cut-off Frequency (-3 dB) vs. Collector Current

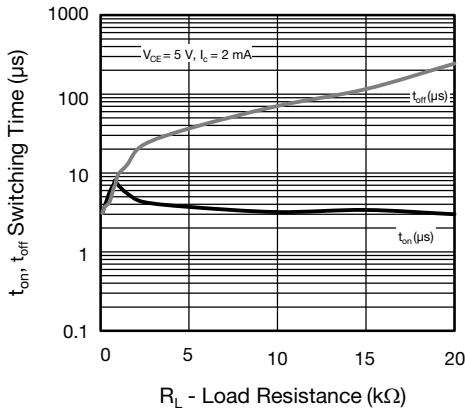


Fig. 16 - Switching Time vs. Load Resistance

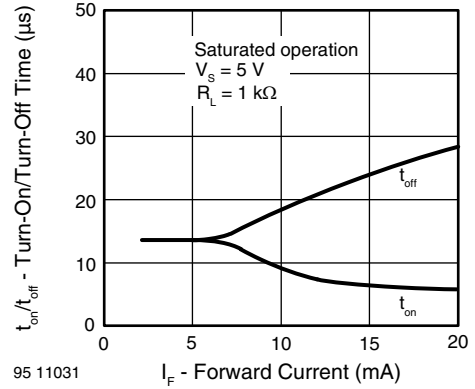


Fig. 18 - Turn-On/Turn-Off Time vs. Forward Current

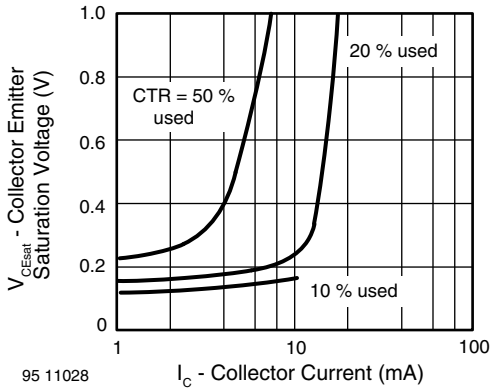


Fig. 17 - Collector Emitter Saturation Voltage vs. Collector Current

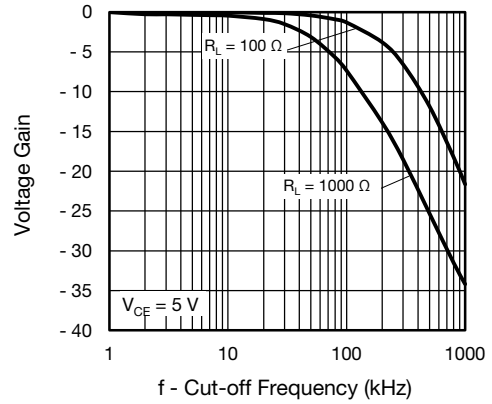
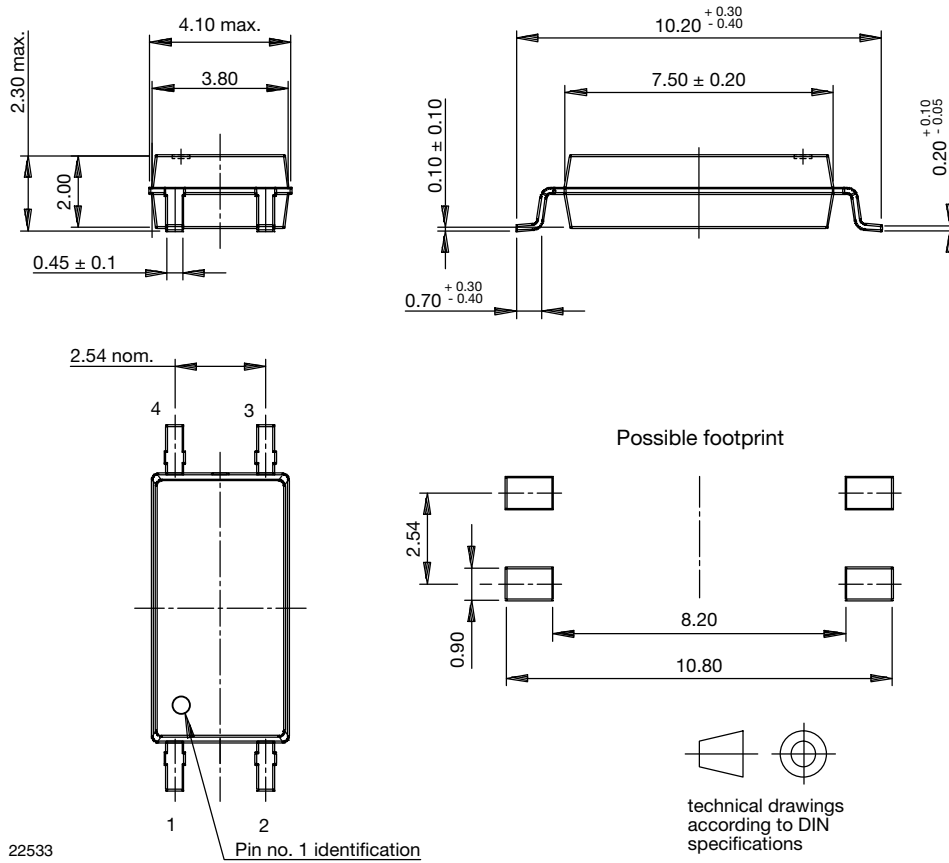
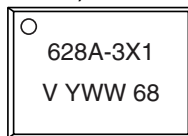


Fig. 19 - Voltage Gain vs. Cut-off Frequency

**PACKAGE DIMENSIONS** in millimeters



**PACKAGE MARKING** (example of VOL628A-3X001T)



**Notes**

- Only option 1 is reflected in the package marking with the characters "X1".
- Tape and reel suffix (T) is not part of the package marking.

**TAPE AND REEL DIMENSIONS** in millimeters

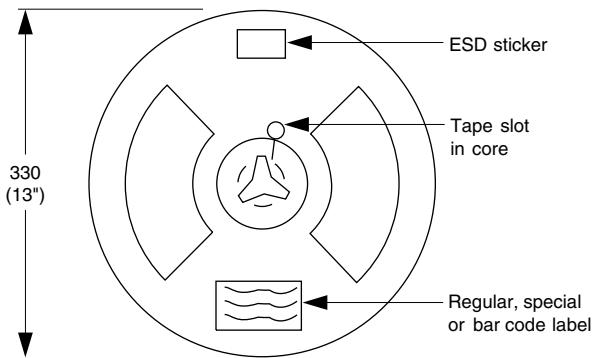


Fig. 20 - Reel Dimensions (3000 units per reel)

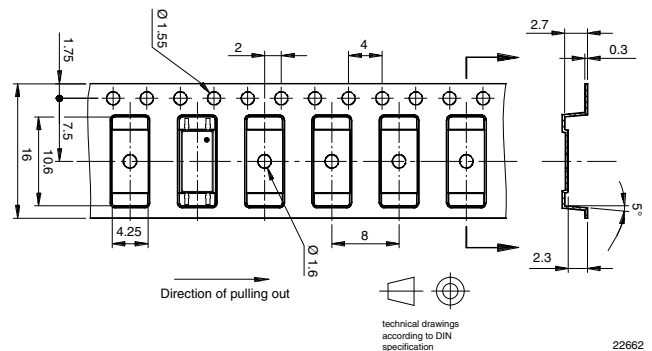


Fig. 21 - Tape Dimensions



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